	Туре	L #	Hits	Search Text	DBs
1	BRS	L3	2171	"257"/\$.ccls. and (work adj function ionization adj potential) and organic	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
2	BRS	L4	168	"257"/\$.ccls. and (work adj function ionization adj potential) and organic adj semiconductor adj3 (layer material)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B
3	BRS	L15	5	"349"/\$.ccls. and (work adj function ionization adj potential) and organic adj semiconductor adj3 (layer material)	US- PGPUB; USPAT; EPO; JPO; DERWEN T; IBM_TD B